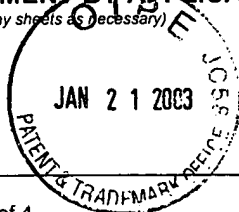


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Application Number	09/816603
Filing Date	March 23, 2001
First Named Inventor	Jenson, Mark
Group Art Unit	1745
Examiner Name	Unknown

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Attorney Docket No: 1327.009US1

**US PATENT DOCUMENTS**

Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
RAM	US-4,299,890	11/10/1981	Rea, J., et al	429	124	
	US-4,333,808	06/08/2002	Bhattacharyya, A., et al	204	192 D	02/13/1981
	US-4,365,107	12/21/1982	Yamauchi, Y.	136	258	02/19/1981
	US-4,730,383	03/15/1988	Balkanski, M.	29	623.5	05/05/1986
	US-4,740,431	04/26/1988	Little, R.	429	9	
	US-5,051,274	09/24/1991	Goldner, R., et al	427	38	09/11/1989
	US-5,151,848	09/29/1992	Finello, D.	361	502	08/24/1990
	US-5,171,413	12/15/1992	Arntz, F., et al	204	192.15	09/16/1991
	US-5,180,645	01/19/1993	More, G.	429	127	03/01/1991
	US-5,189,550	02/23/1993	Goldner, R., et al	359	273	12/13/1991
	US-5,192,947	03/09/1993	Neustein, S.	340	825.44	02/02/1990
	US-5,338,625	08/16/1994	Bates, J., et al	429	193	
	US-5,411,592	05/02/1995	Ovshinsky, S., et al	118	718	06/06/1994
	US-5,425,966	06/20/1995	Winter, C., et al	427	255.1	10/27/1994
	US-5,426,561	06/20/1995	Yen, S., et al	361	502	03/31/1994
	US-5,445,906	08/29/1995	Hobson, D., et al	429	162	08/03/1994
	US-5,448,110	09/05/1995	Tuttle, J., et al	257	723	09/14/1993
	US-5,468,521	11/21/1995	Kanai, M., et al	427	575	11/02/1994
	US-5,549,989	08/27/1996	Anani, A.	429	193	12/20/1993
	US-5,571,749	11/05/1996	Matsuda, K., et al	437	113	12/28/1994
	US-5,626,976	05/06/1997	Blanton, G., et al	429	9	07/24/1995
	US-5,644,207	07/01/1997	Lew, A., et al	320	5	04/16/1996
	US-5,695,885	12/09/1997	Malbi, S.	429	7	12/06/1995
	US-5,763,058	06/09/1998	Isen, I., et al	428	209	10/07/1995
	US-5,872,080	02/16/1999	Arendt, P., et al	505	238	04/19/1995
	US-5,978,207	11/02/1999	Anderson, W., et al	361	311	10/30/1997
	US-6,094,292	07/25/2000	Goldner, R., et al	359	265	02/20/1998
	US-6,222,117	04/24/2001	Shiozaki, A.	136	256	12/29/1998
	US-6,236,061	05/22/2001	Walpta, L.	257	40	01/08/1999
	US-6,264,709	07/24/2001	Yoon, Y., et al	29	623.5	

**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T <sup>2</sup>
RAM	DE-19948742	12/28/2000	Scherber, W., et al	H01 G	9/058	
	EP-0078404	05/11/1983	Craig, D. R.	H01 M	14/00	

EXAMINER

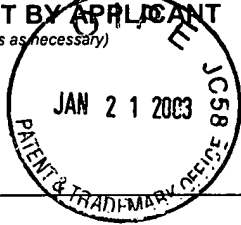
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T <sup>2</sup>
RAM	EP-0410627	01/30/1991	Okuno, S., et al	C23 C	14/08	
	EP-0643544 ✓	08/30/1994	Ludwig, Hans	H04 Q	7/32	
	EP-0860888	08/26/1998	Allen, R. J., et al	H01 M	8/10	
	EP-0867752	09/30/1998	Giron, Jean-Christophe	G02F	1/15	
	GB-2318127	04/15/1998	Nadir, A., et al	C23 C	14/06	
	JP-03205757	09/09/1991	Hayakawa, T.	H01 M	2/10	
	JP-03262697	11/22/1991	Watanabe, T.	B42D	15/10	
	JP-06067018	03/11/1994	Yokoe, K.	G02 B	5/28	
	JP-06223805	08/12/1994	Murata, K.	H01 M	2/22	
	JP-07-050229	02/21/1995	Katsumi, Y.	H01 G	9/028	
	JP-07006933	01/10/1995	Yoshino, K.	H01 G	9/00	
	JP-07057739	03/03/1995	Ezaka, Y.	H01 M	4/88	
	JP-08017179	01/19/1996	Kagawa, H.	G11 B	33/12	
	JP-08236105	09/13/1996	Nishiyama, S.	H01 M	4/04	
	JP-08287901	11/01/1996	Ogata, K.	H01 M	4/04	
	JP-08293310	05/11/1996	Kawashima, T.	H01 M	8/02	
	JP-09035233	02/07/1997	Ishikawa, J.	G11 B	5/66	
	JP-09211204	08/15/1997	Mochizuki, K.	G02 B	1/11	
	JP-10021896	01/23/1998	Muranaka, T.	H01 M	2/22	
	JP-10021933	01/23/1998	Fujitani, Y.	H01 M	4/86	
	JP-2000188113	07/04/2000	Roppongi, Y.	H01 M	6/18	

EXAMINER

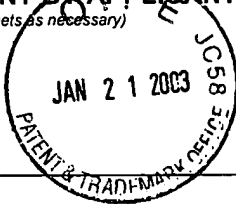
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T <sup>2</sup>
RAM	JP-58126679	07/28/1983	Tetsuichi, K. ✓	H01 M	10/40	
	JP-60012679	01/23/1985	Sekido, S. ✓	H01 M	10/36	
	JP-6111828	04/22/1994	Susumu, H.	H01 M	4/86	
	JP-6196178	07/15/1994	Hiroshi, N.	H01 M	8/02	
	JP-62044960	02/26/1987	Maeda, Y.	H01 M	10/38	
	WO-92/15140	09/03/1992	Armand, M., et al	H02J	7/00	
	WO-92/16025	09/17/1992	More, G.	H01 M	2/22	
	WO-92/19090	10/29/1992	Radmall, P., et al	H05K	1/16	
	WO-93/14612	07/22/1993	Dubruco, D.	H05K	1/00	
	WO-95/143111	05/26/1995	Ovshinsky, et al	H01 M	6/18	
	WO-97/38453	10/16/1997	VAn Lerberghe, S.	H01 M	2/02	
	WO-97/39491	10/23/1997	Lew, Ark L., et al	H01 M	10/44	
	WO-98/13743	04/02/1998	Charkey, A., et al	G06F	1/26	
	WO-98/47196	10/22/1998	Neudecker, B.	H01 M	4/58	
	WO-99/25908	05/27/1999	Do, K., et al	C30B	23/02	
	WO-99/33124	07/01/1990	Wolf, M.	H01 M	2/10	

**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
RAM		DUNN, D., et al. , "MoS2 Deposited by ion beam assisted deposition: 2H ot random layer structure.", Naval Research Laboratory, (1998), pp. 3001-3007	No month/ date available
		GOLDNER, R., "Ambient temperature synthesis of polycrystalline thin films of lithium cobalt oxide with controlled crystallites orientations", <u>Electrochemical Soc. Proceedings</u> , 98, (1999), pp. 268-273	
		GOLDNER, R., et al. , "Ambient Temperature Synthesis of Polycrystalline Thin Films of Lithium Cobalt Oxide with Controlled Crystallites' Orientation", <u>Mat. Res. Soc. Symp. Proc.</u> , 548, (1998), pp. 131-136	
		KYOKANE, J., et al. , "Organic Solid Capacitor with Conducting Thin Films as Electrolyte by Ion-Beam-Assisted Deposition", <u>Journal of Power Sources</u> , 60,	

EXAMINER

RAM

DATE CONSIDERED

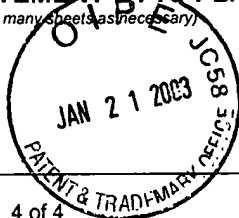
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**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

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		(1996),pp. 151-155	
RAM		LIU, W.,et al. , "Deposition, Structural Characterization, and Broadband (1KHz-40GHz) Dielectric Behavior of BaTi2-xOy Thin Films", <u>Mat. Res. Soc. Symp. Proc.</u> , 310, (1993),pp. 157-162	No months / date available
		MARTIN, P.,et al. , "Modification of the optical and structural properties of dielectric ZrO2 films by ion-assisted deposition", <u>Journal of Applied Physics</u> , 55(1), (1984),pp. 235-241	
		VEREDA, F., "A study of electronic shorting in IBDA-deposited Lipon films", <u>Journal of Power Sources</u> , 89(2), (2000),pp. 201-205	
		ZEITLER, M.,et al. , "In Situ Stress Analysis of Boron Nitride Films Prepared by Ion Beam Assisted Deposition", <u>Nuclear Instruments and Methods in Physics Research B</u> , 139, (1998),pp. 327-331	

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